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Docket No.: M4065.0703/P703-A
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of:
Kristy A. Campbell et al.

Patent No.: 7,067,348

Issued: June 27, 2006

For: METHOD OF FORMING A
PROGRAMMABLE MEMORY CELL AND
CHALCOGENIDE STRUCTURE

Certificate
AUG 11 2006
of Correction

**REQUEST FOR CERTIFICATE OF CORRECTION
PURSUANT TO 37 CFR 1.322**

Attention: Certificate of Correction Branch
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Certificate
AUG 11 2006
of Correction

Dear Sir:

Upon reviewing the above-identified patent, Patentees noted typographical errors which should be corrected.

In the Other Publications portion of the References Cited section, the PTO made the following errors to be corrected:

"Bernede, J.C.; Khelil, A.; Kettaf, M.; Conan, A., Transition from S- to N-type differential negative resistance in $\text{Al-Al}_2\text{O}_3\text{-Ag}_{2-x}\text{Se}_{1+x}$ thin film structures, Phys. Stat. Sol. (a) 74 (1982) 217-224."

should read

AUG 11 2006

--Bernede, J.C.; Khelil, A.; Kettaf, M.; Conan, A., Transition from S- to N-type differential negative resistance in Al-Al₂O₃-Ag_{2-x}Se_{1+x} thin film structures, Phys. Stat. Sol. (a) 74 (1982) 217-224.--; and

"Belin, R.; Zerouale, A.; Pradel, A.; Ribes, M., Ion dynamics in the argyrodite compound Ag₇GeSe₅I: non-Arrhenius behavior and complete conductivity spectra, Solid State Ionics."

should read

--Belin, R.; Zerouale, A.; Pradel, A.; Ribes, M., Ion dynamics in the argyrodite compound Ag₇GeSe₅I: non-Arrhenius behavior and complete conductivity spectra, Solid State Ionics, 143 (2001) 445-455.--.

The errors were not in the application as filed or amended by Applicants; accordingly no fee is required.

Transmitted herewith is a proposed Certificate of Correction effecting such amendment. Patentees respectfully solicit the granting of the requested Certificate of Correction.

Dated: August 9, 2006

Respectfully submitted,

By 

Thomas J. D'Amico

Registration No.: 28,371

Elizabeth Parsons

Registration No.: 52,499

DICKSTEIN SHAPIRO LLP

1825 Eye Street, NW

Washington, DC 20006-5403

(202) 420-2200

Attorneys for Applicants

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**UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION**

Page 1 of 1

PATENT NO. : 7,067,348
APPLICATION NO. : 10/825,319
ISSUE DATE : June 27, 2006
INVENTORS : Kristy A. Campbell et al.

It is certified that errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the Other Publications portion of the References Cited section, the following errors are corrected:

"Bernede, J.C.; Khelil, A.; Kettaf, M.; Conan, A., Transition from S- to N-type differential negative resistance in Al-Al₂O₃-Ag_{2-x}Se_{1+x} thin film structures, Phys. Stat. Sol. (a) 74 (1982) 217-224."

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MAILING ADDRESS OF SENDER (Please do not use customer number below):

Thomas J. D'Amico
DICKSTEIN SHAPIRO LLP
1825 Eye Street, NW
Washington, DC 20006-5403

1

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